SPECIFICATION T60404-N4646-X654 Item no.: 28.01.2022 K-no.: 24510 Date: 50 A Current Sensor modul for 5V-Supply Voltage For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit (electronic circuit) Customers Part no.: Page 1 of Customer: Standard type Characteristics Description **Applications** Excellent accuracy Mainly used for stationary operation in industrial Closed loop (compensation) applications: Current Sensor with magnetic Very low offset current AC variable speed drives and servo motor field probe Very low temperature dependency and offset Printed circuit board mounting current drift Static converters for DC motor drives Casing and materials UL-listed Very low hysteresis of offset current Short response time Battery supplied applications Switched Mode Power Supplies (SMPS) Wide frequency bandwidth Compact design Power Supplies for welding applications Uninterruptible Power Supplies (UPS) Reduced offset ripple **Electrical data - Ratings** Primary nominal r.m.s. current IPN V_{out} Output voltage @ IP $2.5 \pm (0.625*I_P/I_{PN})$ ٧ Output voltage @ Ip=0, Ta=25°C 2.5 ± 0.0058 Vout Reference voltage 2.5 ± 0.005 V V_{Ref} K_N Turns ratio 1...3:1400 Accuracy - Dynamic performance data

4

		mın.	typ.	max.	Unit
I _{P,max}	Max. measuring range	±150			
Χ	Accuracy @ I _{PN} , T _A = 25°C			0.7	%
εL	Linearity			0.1	%
V_{out} -2,5 V	Offset voltage @ I _P =0, T _A = 25°C			±5.8	mV
$\Delta V_{out}/2,5V/\Delta T$	Temperature drift of Vout @ IP=0, TA= -4085°C		13	26	ppm/K
tr	Response time @ 90% von IPN		300		ns
Δt (I _{P,max})	Delay time at di/dt = 100 A/μs		200		ns
f	Frequency bandwidth	DC200			kHz
and the state of t					

General data

		min.	typ.	max.	Unit
TA	Ambient operating temperature	-40		+85	°C
Ts	Ambient storage temperature	-40		+85	°C
m	Mass		12		g
Vc	Supply voltage	4.75	5	5.25	V
Ic	Current consumption		15		mA

Constructed and manufactored and tested in accordance with EN 61800-5-1 (Pin 1 - 6 to Pin 7 - 9) Reinforced insulation, Insulation material group 1, Pollution degree 2

Sclear	Clearance (compor	nent without solder pad)	7.5		mm
Screep	Creepage (compon	ent without solder pad)	8.0		mm
V _{sys}	System voltage	overvoltage category 3	RMS	300	V
V_{work}	Working voltage	(tabel 7 acc. to EN61800-5-1)			
		overvoltage category 2	RMS	650	V
U_{PD}	Rated discharge v	oltage	peak value	1320	V
Max. potential diffe	erence acc. to UL 5	RMS	600	V_{AC}	

Date	Name	Issue	Amendment						
28.01.2022	NSch.	83	Applicable do	oplicable document change on sheet 3. "The color of the plastic material added. Minor change.					
11.08.14	KRe.	83	Marking: Issu	arking: Issue "83" added. CN-14-073.					
Hrsg.: KB-E Bea		arb: DJ		KB-PM: Sn.			freig.: SB released		



SPECIFICATION

Item no.: T60404-N4646-X654

K-no.: 24510

Customer:

50 A Current Sensor modul for 5V-Supply Voltage

For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit (electronic circuit) Date: 28.01.2022

Connections: 1...6: Ø 1 mm

7...9: 0,46*0,46 mm

Customers Part no.: Page 2 of 4

Mechanical outline (mm):

Standard type

General tolerances DIN ISO 2768-c

Tolerances grid distance ±0,2mm

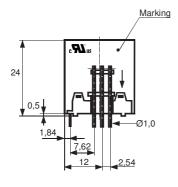
514 12,7 9 1 1 3 22,2

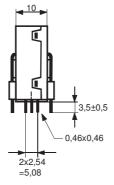
DC = Date Code F = Factory

Code ory



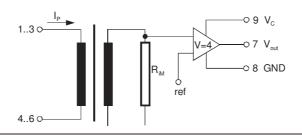
UL-sign 4646-X654-83 F DC







Schematic diagram



Possibilities of wiring (@ T_A = 85°C)

primary windings	primar RMS	y current maximal	output current RMS	turns ratio	primary resistance	wiring
N _P	I _P [A]	$\hat{\mathbf{I}}_{P,max}\left[\mathbf{A}\right]$	$I_S(I_P)$ [mA]	K_N	$R_P \ [m\Omega]$	
1	50	±150	2.5±0.625	1:1400	0.33	3 1
2	12	±75	2.5±0.300	2:1400	1.5	3 1
3	8	±50	2.5±0.300	3:1400	3	> ³ / ₄ ¹ / ₆ >

Hrsg.: KB-E	Bearb: DJ	KB-PM: Sn.		freig.: SB released
	acoigner	OTICOIC		

SPECIFICATION T60404-N4646-X654 Item no.: Date: 28.01.2022 K-no.: 24510 50 A Current Sensor modul for 5V-Supply Voltage For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit (electronic circuit) Customers Part no .: Page 3 of 4 Customer: Standard type

Electrical Data

		min.	typ.	max.	Unit
V _{Ctot}	Maximum supply voltage (without function)			7	V
Ic	Supply Current with primary current	15m	$A + I_p * K_N + V_c$	out/R _L	mA
lout,SC	Short circuit output current		±20		mA
R_P	Resistance / primary winding @ T _A =25°C		1		$m\Omega$
Rs	Secondary coil resistance @ T _A =85°C			35	Ω
R_{i} , (V_{out})	Output resistance of Vout			1	Ω
RL	External recommended resistance of Vout	1			kΩ
C_L	External recommended capacitance of Vout			500	pF
$\Delta X_{Ti}/\Delta T$	Temperature drift of X@T _A = -40 +85 °C			40	ppm/K
$\Delta V_0 = \Delta (V_{out} - 2.5V)$	Sum of any offset drift including:		5	10	mV
V_{0t}	Long term drift of V ₀		1		mV
V_{0T}	Temperature drift von V ₀ @ T _A = -40+85°C		4		mV
V_{0H}	Hysteresis of V_{out} @ I_{P} =0 (after an overload of 10 x I_{PN}))		1	mV
$\Delta V_0/\Delta V_C$	Supply voltage rejection ratio			1	mV/V
V _{OSS}	Offsetripple (with 1 MHz- filter first order)			70	mV
Voss	Offsetripple (with 100 kHz- filter firdt order)		4	10	mV
Voss	Offsetripple (with 20 kHz- filter first order)		1	2	mV
Ck	Maximum possible coupling capacity (primary - sec	condary)	5	10	pF
	Mechanical stress according to M3209/3			00	
	Settings: 10 – 2000 Hz, 1 min/Octave, 2 hours			30g	

<u>Inspection</u> (Measurement after temperature balance of the samples at room temperature) SC = significant characteristic

Vout (SC)	(V)	M3011/6:	Output voltage vs. internal reference (Ip=3x10As, 40-80Hz)	625±1%	mV
V _{out} -2.5V	$(I_{P}=0)(V)$	M3226:	Offset voltage	± 5.8	mV
V _d	(V)	M3014:	Test voltage, rms, 1 s pin 1 – 6 vs. pin 7 – 9	1.5	kV
Ve	(AQL	1/S4)	Partial discharge voltage acc.M3024 (RMS)	1400	V
			with V _{vor} (RMS)	1750	V

Type Testing (Pin 1 - 6 to Pin 7 - 9)

Designed according standard EN 50178 with insulation material group 1

V_W	HV transient test according (to M3064) (1,2 µs / 50 µs-wave fo	8	kV	
V_d	Testing voltage to M3014	(5 s)	3	kV
Ve	Partial discharge voltage acc.M3024 (RMS)		1400	V
	with V _{vor} (RMS)		1750	V

Applicable documents

Current direction: A positive output current appears at point I_s , by primary current in direction of the arrow. Enclosures according to IEC529: IP50.

Further standards UL 508 ; file E317483, category NMTR2 / NMTR8 $\,$

Temperature of the primary conductor should not exceed 110°C.

"The color of the plastic material is not specified and the current sensor can be supplied in different colors

(e.g. brown, black, white, natural). This has no effect on the specifications or UL approval."

Hrsg.: KB-E	Bearb: DJ	KB-PM: Sn.		freig.: SB
editor	designer	check		released



SPECIFICATION

Item no.: T60404-N4646-X654

K-no.: 24510

50 A Current Sensor modul for 5V-Supply Voltage

For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (high power) and secondary circuit

(electronic circuit)

Customer: Standard type

Customers Part no.:

Page

Date:

of

4

28.01.2022

4

Explanation of several of the terms used in the tablets (in alphabetical order)

tr: Response time (describe the dynamic performance for the specified measurement range), measured as delay time at $I_P = 0.9 \cdot I_{PN}$ between a rectangular current and the output voltage V_{OUI} (I_D)

 Δt (I_{Pmax}): Delay time (describe the dynamic performance for the rapid current pulse rate e.g short circuit current) measured between I_{Pmax} and the output voltage V_{out}(I_{Pmax}) with a primary current rise of dip/dt \geq 100 A/ μ s.

 U_{PD} Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage V_e U_{PD} = $\sqrt{2} * V_e / 1.5$

V_{vor} Defined voltage is the RMS valve of a sinusoidal voltage with peak value of 1,875 * U_{PD} required for partial discharge test in IEC 61800-5-1

 $V_{vor} = 1.875 * U_{PD} / \sqrt{2}$

 V_{svs} System voltage RMS value of rated voltage according to IEC 61800-5-1

Vwork Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

 V_0 : Offset voltage between V_{out} and the rated reference voltage of $V_{ref} = 2,5V$.

 $V_o = V_{out}(0) - 2,5V$

 V_{0H} : Zero variation of V_0 after overloading with a DC of tenfold the rated value

 V_{0t} : Long term drift of V_0 after 100 temperature cycles in the range -40 bis 85 °C.

X: Permissible measurement error in the final inspection at RT, defined by

 $X = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{out}(0)}{0.625V} - 1 \right| \%$

X_{ges}(I_{PN}): Permissible measurement error including any drifts over the temperature range by the current measurement I_{PN}

 $X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - 2,5V}{0,625V} - 1 \right| \% \text{ or } X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{ref}}{0,625V} - 1 \right| \%$

 $\varepsilon_{\rm L} : \qquad \qquad \text{Linearity fault defined by} \qquad \varepsilon_{\rm L} = 100 \cdot \left| \frac{I_{\rm P}}{I_{\rm PN}} - \frac{V_{\it out}(I_{\it P}) - V_{\it out}(0)}{V_{\it out}(I_{\it PN}) - V_{\it out}(0)} \right| \, \%$